# PDTA144E series

PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$ 

Rev. 8 — 14 November 2011

**Product data sheet** 

### 1. Product profile

### 1.1 General description

PNP Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number				NPN	Package
	NXP	JEITA	JEDEC	complement	configuration
PDTA144EE	SOT416	SC-75	-	PDTC144EE	ultra small
PDTA144EM	SOT883	SC-101	-	PDTC144EM	leadless ultra small
PDTA144ET	SOT23	-	TO-236AB	PDTC144ET	small
PDTA144EU	SOT323	SC-70	-	PDTC144EU	very small

### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	



## 2. Pinning information

Table 3. **Pinning** Simplified outline **Graphic symbol** Pin Description SOT23; SOT323; SOT416 1 input (base) 3 GND (emitter) 2 3 output (collector) 2 006aaa144 sym003 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

## 3. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
PDTA144EE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTA144EM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883				
PDTA144ET	-	plastic surface-mounted package; 3 leads	SOT23				
PDTA144EU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

## 4. Marking

Table 5. Marking codes

Marking code <sup>[1]</sup>
07
DR
*07
*07

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

Table 6. Limiting values

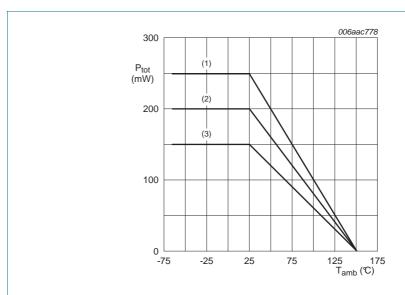
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-50	V
$V_{CEO}$	collector-emitter voltage	open base	-	-50	V
$V_{EBO}$	emitter-base voltage	open collector	-	-10	V
VI	input voltage				
	positive		-	+10	V
	negative		-	-40	V
I <sub>O</sub>	output current		-	-100	mA
I <sub>CM</sub>	peak collector current	$single \ pulse; \\ t_p \leq 1 \ ms$	-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	PDTA144EE (SOT416)		[1][2] _	150	mW
	PDTA144EM (SOT883)		[2][3]	250	mW
	PDTA144ET (SOT23)		<u>[1]</u> -	250	mW
	PDTA144EU (SOT323)		<u>[1]</u> -	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70  $\mu m$  copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

Fig 1. Power derating curves

### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTA144EE (SOT416)		[1][2]	-	830	K/W
	PDTA144EM (SOT883)		[2][3]	-	500	K/W
	PDTA144ET (SOT23)		[1] -	-	500	K/W
	PDTA144EU (SOT323)		<u>[1]</u> _	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.

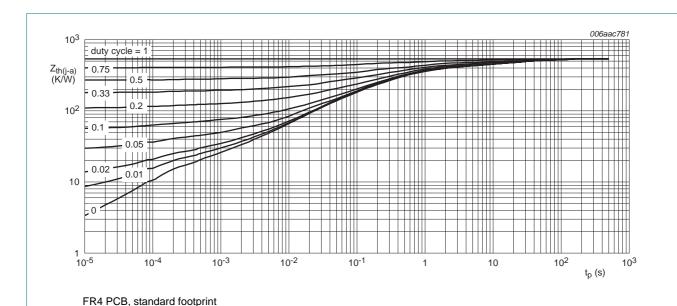


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA144EE (SOT416); typical values

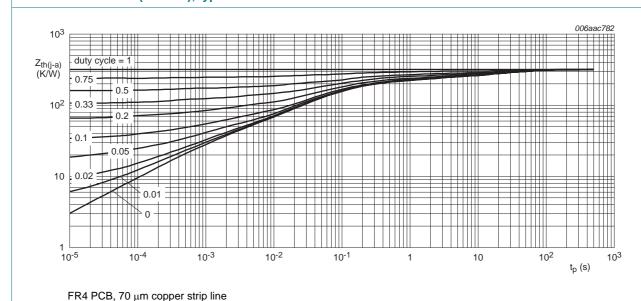


Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA144EM (SOT883); typical values

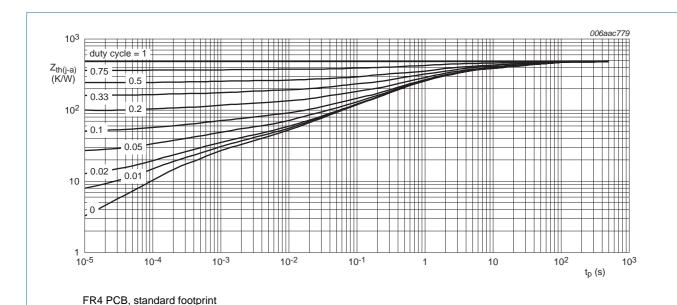


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA144ET (SOT23); typical values

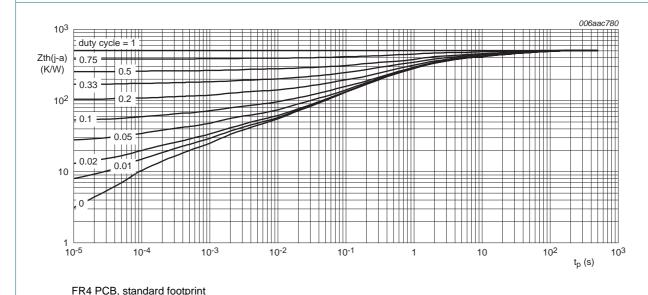


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTA144EU (SOT323); typical values

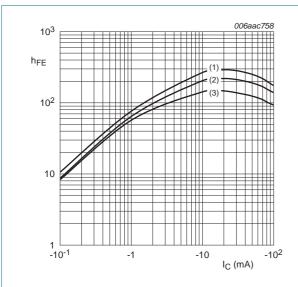
### 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	-1	μΑ
	cut-off current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-90	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	80	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	-	-	-150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-1.2	-0.8	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = -0.3 \text{ V}; I_{C} = -2 \text{ mA}$	-3	-1.6	-	V
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		8.0	1	1.2	
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE} = -5 \text{ V; } I_{C} = -10 \text{ mA;}$ f = 100 MHz	-	180	-	MHz

<sup>[1]</sup> Characteristics of built-in transistor



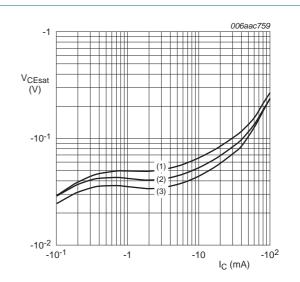
$$V_{CE} = -5 \text{ V}$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 6. DC current gain as a function of collector current; typical values



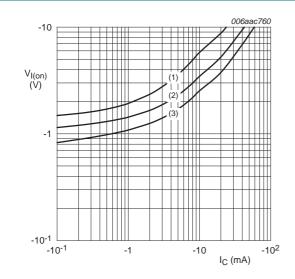
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values



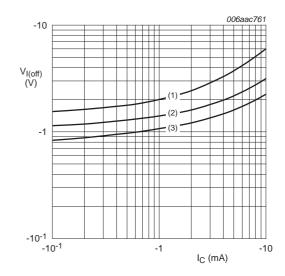
$$V_{CE} = -0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 8. On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 9. Off-state input voltage as a function of collector current; typical values

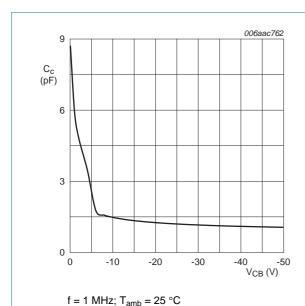
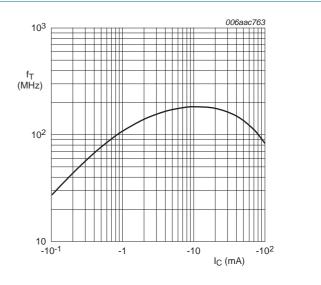


Fig 10. Collector capacitance as a function of collector-base voltage; typical values of built-in transistor



 $V_{CE} = -5 \text{ V}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

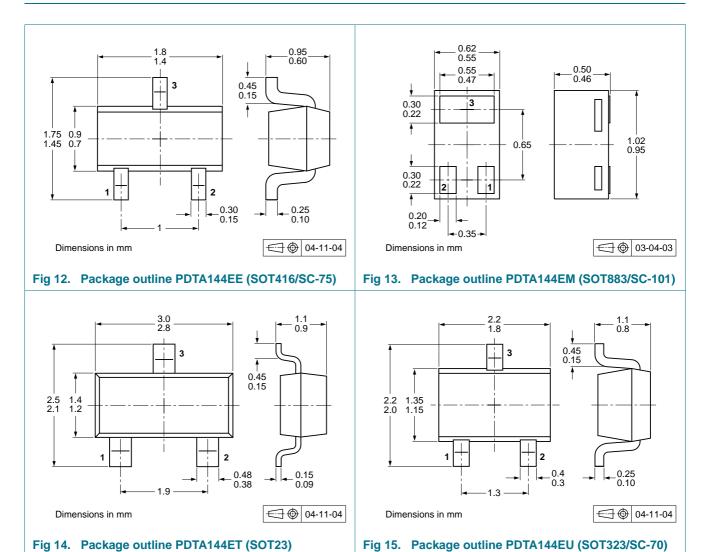
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



## 10. Packing information

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	Packing quantity			
			3000	5000	10000		
PDTA144EE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTA144EM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315		
PDTA144ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235		
PDTA144EU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135		

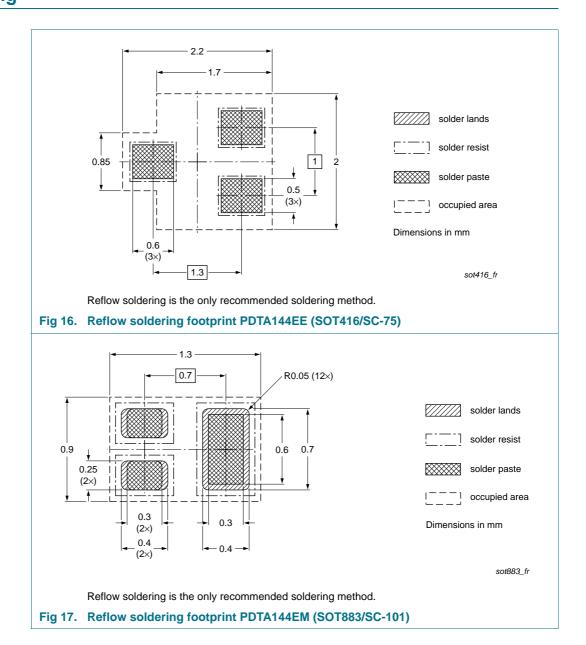
[1] For further information and the availability of packing methods, see Section 14.

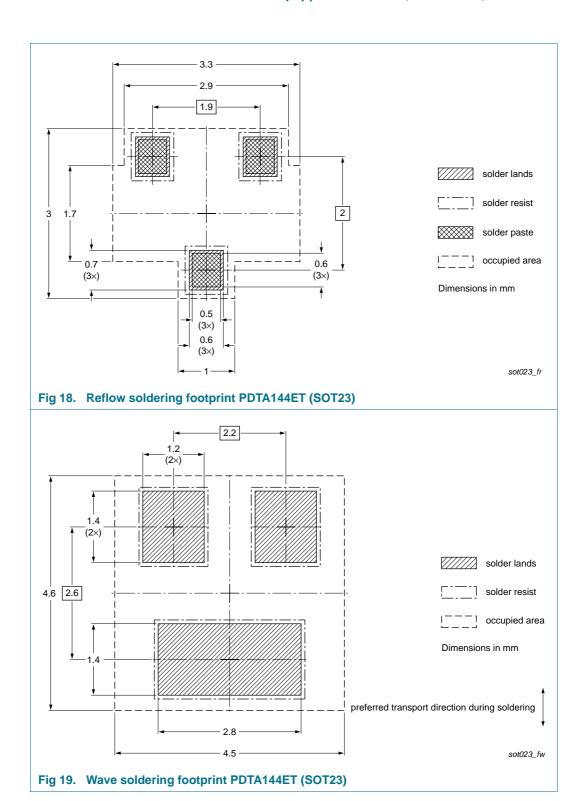
PDTA144E\_SER

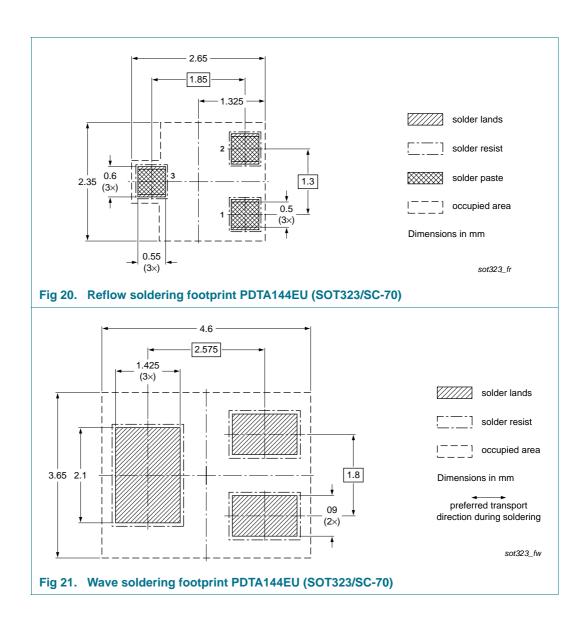
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## 11. Soldering







## 12. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PDTA144E_SERIES v.8	20111114	Product data sheet	-	PDTA144E_SERIES v.7		
Modifications:		of this document has been f NXP Semiconductors.	redesigned to comply w	ith the new identity		
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
	<ul> <li>Type numbers PDTA144EEF, PDTA144EK and PDTA144ES removed.</li> </ul>					
	Section 1 "Product profile": updated					
	<ul> <li>Section 3 "Ordering information": added</li> </ul>					
	<ul> <li>Section 4 "Marking": updated</li> </ul>					
	• Figure 1 to 11: added					
	Section 6 "Thermal characteristics": updated					
	Table 8 "Characteristics": V <sub>i(on)</sub> redefined to V <sub>I(on)</sub> on-state input voltage, V <sub>i(off)</sub> redefined					
	to V <sub>I(off)</sub> off-s	state input voltage, I <sub>CEO</sub> up	dated, f <sub>T</sub> added			
	Section 8 "Test information": added					
	<ul> <li>Section 9 "P</li> </ul>	ackage outline": supersed	ed by minimized packag	e outline drawings		
	• Section 10 "	Packing information": adde	ed			
	Section 11 "S	Soldering": added				
	d					
PDTA144E_SERIES v.7	20040805	Product data sheet	-	PDTA144E_SERIES v.6		
PDTA144E_SERIES v.6	20030410	Product specification	-	-		

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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# **PDTA144E** series

PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$ 

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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# **PDTA144E series**

PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 47 k $\Omega$ 

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